

# MBR30H90PT, MBR30H100PT

Vishay General Semiconductor

### **Dual Common-Cathode High-Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PIN 1 O PIN 2 PIN 3 O CASE

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 2 x 15 A					
V <sub>RRM</sub>	90 V, 100 V				
I <sub>FSM</sub>	265 A				
V <sub>F</sub>	0.67 V				
I <sub>R</sub>	5.0 µA				
T <sub>J</sub> max.	175 °C				

### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-247AD (TO-3P)

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR30H90PT MBR30H100PT		UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	90	100	V	
Working peak reverse voltage	V <sub>RWM</sub>	90	100	V	
Maximum DC blocking voltage	V <sub>DC</sub>	90	100	V	
Maximum average forward rectified current	I <sub>F(AV)</sub>	30		А	
per diode		15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	265		А	
Peak repetitive reverse surge current at $t_p = 2 \ \mu s$ , 1 kHz per diode	I <sub>RRM</sub>	1.0		А	
Non-repetitve avalanche energy ( $I_{AS} = 0.5 \text{ A}, L = 60 \text{ mH}$ ) per diode	E <sub>AS</sub>	7.5		mJ	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	TJ, T <sub>STG</sub>	- 65 to + 175		°C	



COMPLIANT

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ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)																		
PARAMETER	SYMBOL	TEST CONDITIONS		MBR30H90PT	MBR30H100PT	UNIT												
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	0.82		V												
		I <sub>F</sub> = 15 A	T <sub>J</sub> = 125 °C	0.67														
		VF ()	VF ()	VF ()	VF ()	VF ()	VF ()	VF	VF ()	VF ()	VF	VF ()	VF \	$I_F = 30 A$	T <sub>J</sub> = 25 °C	0.	93	v
		$I_F = 30 A$	T <sub>J</sub> = 125 °C	0.	80													
Maximum instantaneous reverse current at rated DC blocking voltage per diode	I <sub>R</sub> <sup>(1)</sup>	L (1)	L (1)		T <sub>J</sub> = 25 °C	5	.0	μA										
			T <sub>J</sub> = 125 °C	6	.0	mA												

Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR30H90PT MBR30H100PT		UNIT		
Thermal resistance, junction to case per diode	$R_{ ext{ heta}JC}$	1.6		°C/W		

ORDERING INFORMATION (Example)							
PACKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY		DELIVERY MODE					
TO-220AD	MBR30H100PT-E3/4W	6.13	45	30/tube	Tube		

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

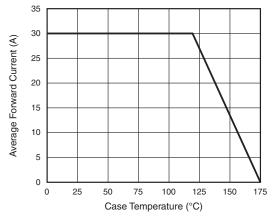


Fig. 1 - Forward Derating Curve

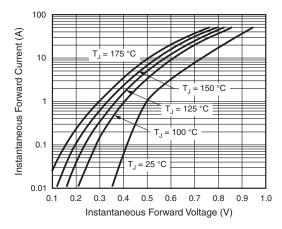


Fig. 2 - Typical Instantaneous Forward Characteristics Per Diode

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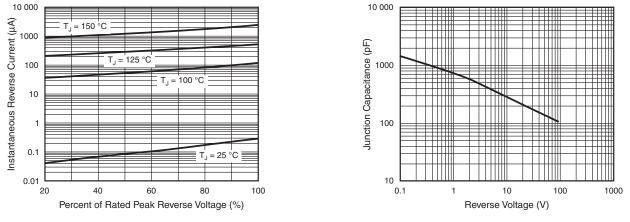
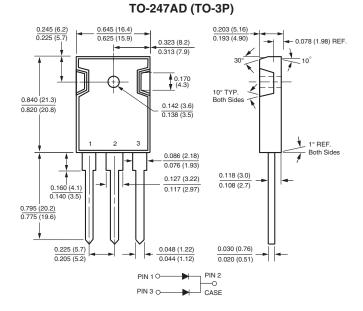


Fig. 4 - Typical Junction Capacitance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

Fig. 3 - Typical Reverse Characteristics Per Diode





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